

Data Sheet Issue:- A1

Rectifier Diode Types W7395ED450 to W7395ED480

Development part number WX566EC480

Absolute Maximum Ratings

| | VOLTAGE RATINGS | MAXIMUM LIMITS | UNITS |
|------|---|-------------------|-------|
| Vrrm | Repetitive peak reverse voltage, (note 1) | 4500-4800 | V |
| Vrsm | Non-repetitive peak reverse voltage, (note 1) | 4600-4900 | V |

| | OTHER RATINGS | MAXIMUM LIMITS | UNITS |
|----------------------|---|-----------------------|------------------|
| I _{F(AV)M} | Maximum average forward current, T _{sink} =55°C, (note 2) | 7395 | А |
| IF(AV)M | Maximum average forward current. Tsink=100°C, (note 2) | 5249 | А |
| I _{F(AV)M} | Maximum average forward current. T _{sink} =100°C, (note 3) | 2830 | А |
| I _{F(RMS)M} | Nominal RMS forward current, T _{sink} =25°C, (note 2) | 13480 | А |
| IF(d.c.) | D.C. forward current, T _{sink} =25°C, (note 4) | 12230 | А |
| IFSM | Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 5) | 73 | kA |
| IFSM2 | Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5) | 80 | kA |
| l²t | $I^{2}t$ capacity for fusing t_{p} =10ms, V_{rm} =60% V_{RRM} , (note 5) | 26.65×10 ⁶ | A ² s |
| l²t | $I^{2}t$ capacity for fusing t_{p} =10ms, V_{rm} ≤10V, (note 5) | 32.00×10 ⁶ | A ² s |
| T _{j op} | Operating temperature range | -40 to +160 | °C |
| T _{stg} | Storage temperature range | -55 to +160 | °C |

Notes:-

1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.

2) Double side cooled, single phase; 50Hz, 180° half-sinewave.

3) Anode side cooled, single phase; 50Hz, 180° half-sinewave.

4) Double side cooled.

5) Half-sinewave, 160°C T_j initial.



Characteristics

| | PARAMETER | MIN. | TYP. | MAX. | TEST CONDITIONS (Note 1) | UNITS |
|------------------|--|------|------|-------|---|-------|
| V _{FM} | Maximum peak forward voltage | - | - | 1.40 | I _{FM} =7000A | V |
| V _{T0} | Threshold voltage | - | - | 0.776 | | V |
| r⊤ | Slope resistance | - | - | 0.087 | | mΩ |
| I _{RRM} | Peak reverse current | - | - | 120 | Rated V _{RRM} | mA |
| Qrr | Recovered charge | - | 19 | 21.5 | | mC |
| Q _{ra} | Recovered charge, 50% Chord | - | 12.1 | - | I _{TM} =2000A, t _p =1000µs, di/dt=10A/µs, | mC |
| Irm | Reverse recovery current | - | 350 | - | Vr=100V | |
| trr | Reverse recovery time, 50% chord | - | 69 | - | | μs |
| | | - | - | 6.0 | Double side cooled | K/kW |
| RthJK | Thermal resistance, junction to heatsink | - | - | 15.3 | Anode side cooled | K/kW |
| | | - | - | 10.1 | Cathode side cooled | K/kW |
| F | Mounting force | 72 | - | 88 | Note 2 | kN |
| Wt | Weight | - | 1.6 | - | | kg |

Notes:-

1) Unless otherwise indicated $T_j=160^{\circ}C$.

 $\dot{2}$ For other clamp forces, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

| Voltage Grade | V _{RRM} V | V _{RSM} V | V _R DC V |
|---------------|-----------------------|-----------------------|------------------------|
| 45 | 4500 | 4600 | 2700 |
| 48 | 4800 | 4900 | 2880 |

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

Where V_{T0} =0.776 V, r_T=0.087 m Ω ,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

| Supplementary Thermal Impedance | | | | | | |
|---------------------------------|---------------|----------------|-----------------|---------|--|--|
| Conduction Angle | 6 phase (60°) | 3 phase (120°) | 1⁄2 wave (180°) | d.c. | | |
| Square wave Double Side Cooled | 0.00657 | 0.00640 | 0.00629 | 0.00600 | | |
| Square wave Anode Side Cooled | 0.01579 | 0.01568 | 0.01559 | 0.01530 | | |
| Square wave Cathode Side Cooled | 0.01056 | 0.01046 | 0.01036 | 0.01010 | | |
| Sine wave Double Side Cooled | 0.00645 | 0.00633 | 0.00618 | | | |
| Sine wave Anode Side Cooled | 0.01574 | 0.01568 | 0.01548 | | | |
| Sine wave Cathode Side Cooled | 0.01051 | 0.01040 | 0.01025 | | | |

| Form Factors | | | | | |
|--|-------|-------|-------|------|--|
| Conduction Angle6 phase (60°)3 phase (120°)½ wave (180°)d.c. | | | | d.c. | |
| Square wave | 2.449 | 1.732 | 1.414 | 1 | |
| Sine wave | 2.778 | 1.879 | 1.57 | | |



5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

| | 25°C Coefficients | 160°C Coefficients |
|---|---------------------------|--------------------|
| А | 0.776718219 | 0.759807124 |
| В | -5.479936×10⁻³ | -0.068941589 |
| С | 1.84995×10⁻⁵ | -1.70435×10⁻⁵ |
| D | 5.892661×10 ⁻³ | 0.016333591 |

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to *n*, *n* is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- $r_t =$ Thermal resistance at time t.
- r_p = Amplitude of p_{th} term.
- τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

| D.C. Double Side Cooled | | | | | | |
|-------------------------|-------------|---------------------------|-------------|---------------------------|--|--|
| Term | erm 1 2 3 4 | | | | | |
| r _p | 0.003173839 | 7.187954×10 ⁻⁴ | 0.001223293 | 7.249536×10 ⁻⁴ | | |
| τρ | 1.340204 | 0.6100118 | 0.08899298 | 0.02902959 | | |

| D.C. Anode Side Cooled | | | | | |
|------------------------|------------|-------------|---------------------------|--|--|
| Term | erm 1 2 3 | | | | |
| r _p | 0.01248921 | 0.002421095 | 4.266685×10 ⁻⁴ | | |
| τρ | 6.830324 | 0.09879866 | 0.01695748 | | |



| D.C. Cathode Side Cooled | | | | | | |
|--------------------------|-------------|-------------|-------------|---------------------------|--|--|
| Term | rm 1 2 3 4 | | | | | |
| rp | 0.005999837 | 0.001857812 | 0.001371868 | 8.726499×10 ⁻⁴ | | |
| τρ | 7.221684 | 0.7978609 | 0.1057334 | 0.02412379 | | |

6.0 Reverse recovery ratings

(i) $Q_{ra}\xspace$ is based on 50% $I_{rm}\xspace$ chord as shown in Fig. 1



(ii) Q_{rr} is based on a $150 \mu s$ integration time i.e.

$$Q_{rr} = \int_{0}^{150\,\mu s} i_{rr}.dt$$

(iii)

$$K Factor = \frac{t_1}{t_2}$$



I²t: V_R=60% V_{RRM}

 I_{FSM} : $V_R \le 10V$ I_{FSM}: V_R=60% V_{RRM}

100

50

Duration of surge (cycles @ 50Hz)

Curves



Figure 2 – Transient thermal impedance

3 5

Duration of surge (ms)

1

10

100000

10000

10

5

1.00E+08

1.00E+07











Figure 5 – Recovered charge, Qra (50% chord)

Figure 7 – Maximum recovery time, trr (50% chord)







Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

Figure 10 – Forward current vs. Power dissipation – Anode Side Cooled



Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled



Figure 11 – Forward current vs. Heatsink temperature – Anode Side Cooled





Outline Drawing & Ordering Information







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